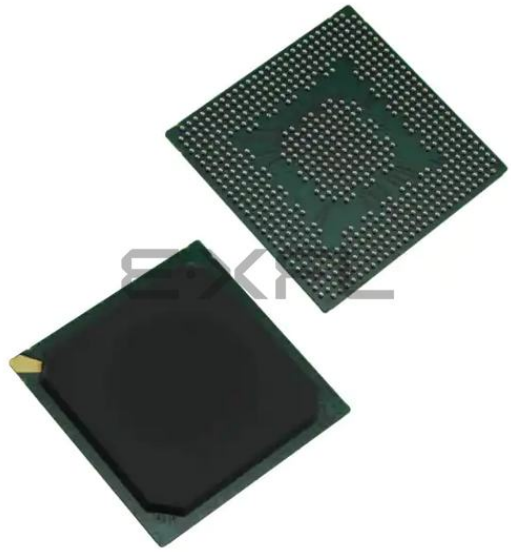

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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	PowerPC e300c3
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	400MHz
Co-Processors/DSP	-
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (2)
SATA	-
USB	USB 2.0 + PHY (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	620-BBGA Exposed Pad
Supplier Device Package	620-HBGA (29x29)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc8314vragda

- One floating point unit and two integer units
- Software-compatible with the Freescale processor families implementing the PowerPC Architecture
- Performance monitor

2.2 Serial Interfaces

The following interfaces are supported in the MPC8314E.

- Two enhanced TSECs (eTSECs)
- Two Ethernet interfaces using one RGMII/MII/RMII/RTBI or SGMII (no GMII)
- Dual UART, one I^2C, and one SPI interface

2.3 Security Engine

The security engine is optimized to handle all the algorithms associated with IPSec, 802.11i, and iSCSI. The security engine contains one crypto-channel, a controller, and a set of crypto execution units (EUs). The execution units are:

- Public key execution unit (PKEU)
  - RSA and Diffie-Hellman (to 4096 bits)
  - Programmable field size up to 2048 bits
  - Elliptic curve cryptography (1023 bits)
  - F2m and F(p) modes
  - Programmable field size up to 511 bits
- Data encryption standard execution unit (DEU)
  - DES, 3DES
  - Two key (K1, K2) or three key (K1, K2, K3)
  - ECB, CBC, CFB-64 and OFB-64 modes for both DES and 3DES
- Advanced encryption standard unit (AESU)
  - Implements the Rinjdael symmetric key cipher
  - Key lengths of 128, 192, and 256 bits
  - ECB, CBC, CCM, CTR, GCM, CMAC, OFB, CFB, XCBC-MAC and LRW modes
  - XOR acceleration
- Message digest execution unit (MDEU)
  - SHA with 160-bit, 256-bit, 384-bit and 512-bit message digest
  - SHA-384/512
  - MD5 with 128-bit message digest
  - HMAC with either algorithm
- Random number generator (RNG)

This table shows the estimated typical I/O power dissipation for this family of devices.

Table 5. MPC8314E Power Dissipation

Interface	Frequency	GV_{DD} (1.8 V)	GV_{DD} (2.5 V)	NV_{DD} (3.3 V)	LVDD1_OFF/ LVDD2_ON (3.3V)	LVDD2 _ON (3.3V)	VDD33PLL, VDD33ANA (3.3V)	SATA_VDD, VDD1IO, VDD1ANA (1.0V)	XCOREVDD, XPADVDD, SDAVDD (1.0V)	Unit
DDR 1 Rs = 22Ω Rt = 50Ω	266MHz, 32 bits	—	0.323	—	—	—	—	—	—	W
	200MHz, 32 bits	—	0.291	—	—	—	—	—	—	W
DDR 2 Rs = 22Ω Rt = 75Ω	266MHz, 32 bits	0.246	—	—	—	—	—	—	—	W
	200MHz, 32bits	0.225	—	—	—	—	—	—	—	W
PCI I/O load = 50pF	33 MHz	—	—	0.120	—	—	—	—	—	W
	66 MHz	—	—	0.249	—	—	—	—	—	W
Local bus I/O load = 20pF	66 MHz	—	—	—	—	0.056	—	—	—	W
	50 MHz	—	—	—	—	0.040	—	—	—	W
eTSEC I/O load = 20pF Multiple by number of interface used	MII, 25MHz	—	—	—	0.008	—	—	—	—	W
	RGMII, 125MHz (3.3V)	—	—	—	0.078	—	—	—	—	W
	RGMII, 125MHz (2.5V)	—	—	—	0.044	—	—	—	—	W
USBDR Controller (ULPI mode) load =20pF	60 MHz	—	—	—	0.078	—	—	—	—	W
USBDR+ Internal PHY (UTMI mode)	480 MHz	—	—	—	0.274	—	—	—	—	W
PCI Express two x1lane	2.5 GHz	—	—	—	—	—	—	—	0.190	W
Other I/O	—	—	—	0.015	—	—	—	—	—	W

5 Clock Input Timing

This section provides the clock input DC and AC electrical characteristics for the MPC8314E.

Table 19. DDR SDRAM Input AC Timing Specifications

At recommended operating conditions with GVDD of (2.5V ± 200 mV)

Controller Skew for MDQS—MDQ 266 MHz 200 MHz	t_{CISKEW}	 –750 –1250	 750 1250	ps	1, 2

Note:

1. t_{CISKEW} represents the total amount of skew consumed by the controller between MDQS[n] and any corresponding bit to be captured with MDQS[n]. This should be subtracted from the total timing budget.
2. The amount of skew that can be tolerated from MDQS to a corresponding MDQ signal is called t_{DISKEW}. This can be determined by the following equation: t_{DISKEW} =+/–(T/4 – abs(t_{CISKEW})) where T is the clock period and abs(t_{CISKEW}) is the absolute value of t_{CISKEW}.

This figure shows the DDR SDRAM input AC timing for the tolerated MDQS to MDQ skew (t_{DISKEW})

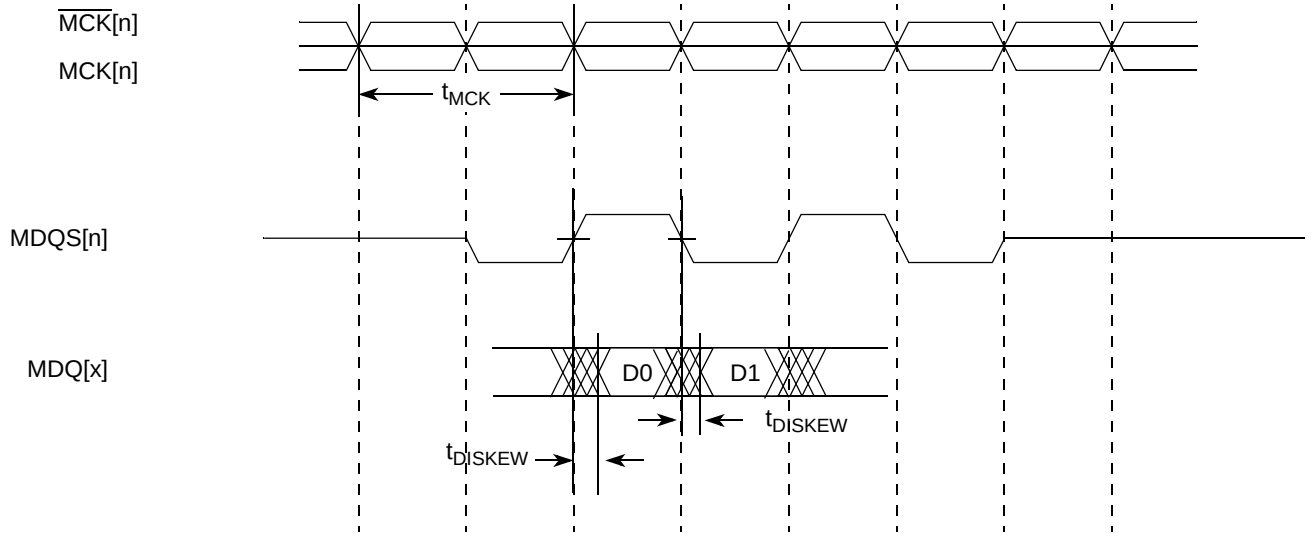

Figure 5. Timing Diagram for t_{DISKEW}

7.2.2 DDR and DDR2 SDRAM Output AC Timing Specifications

Table 20. DDR and DDR2 SDRAM Output AC Timing Specifications

At recommended operating conditions

Parameter	Symbol [1]	Min	Max	Unit	Note
MCK[n] cycle time at MCK[n]/MCK[n] crossing	t_{MCK}	7.5	10	ns	2
ADDR/CMD output setup with respect to MCK 266 MHz 200 MHz	t_{DDKHAS}	 2.9 3.5	 — —	ns	3
ADDR/CMD output hold with respect to MCK 266 MHz 200 MHz	t_{DDKHAX}	 3.15 4.20	 — —	ns	3
MCS[n] output setup with respect to MCK 266 MHz 200 MHz	t_{DDKHCS}	 3.15 4.20	 — —	ns	3

This figure provides the AC test load for the DDR bus.

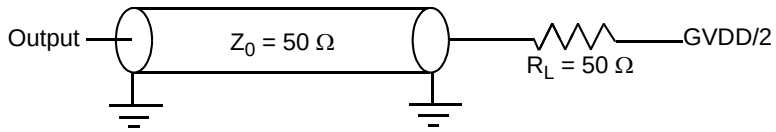

Figure 8. DDR AC Test Load

8 DUART

This section describes the DC and AC electrical specifications for the DUART interface.

8.1 DUART DC Electrical Characteristics

This table lists the DC electrical characteristics for the DUART interface.

Table 21. DUART DC Electrical Characteristics

Parameter	Symbol	Min	Max	Unit
High-level input voltage	V_{IH}	2.1	NVDD + 0.3	V
Low-level input voltage NVDD	V_{IL}	–0.3	0.8	V
High-level output voltage, I_{OH} = –100 μA	V_{OH}	NVDD – 0.2	—	V
Low-level output voltage, I_{OL} = 100 μA	V_{OL}	—	0.2	V
Input current (0 V ≤V_{IN} ≤ NVDD)	I_{IN}	—	± 5	μA

8.2 DUART AC Electrical Specifications

This table lists the AC timing parameters for the DUART interface.

Table 22. DUART AC Timing Specifications

Parameter	Value	Unit	Note
Minimum baud rate	256	baud	—
Maximum baud rate	> 1,000,000	baud	1
Oversample rate	16	—	2

Note:
1. Actual attainable baud rate is limited by the latency of interrupt processing.
2. The middle of a start bit is detected as the eighth sampled 0 after the 1-to-0 transition of the start bit. Subsequent bit values are sampled each sixteenth sample.

9 Ethernet: Three-Speed Ethernet, MII Management

This section provides the AC and DC electrical characteristics for three-speed, 10/100/1000, and MII management.

Table 28. RMII Receive AC Timing Specifications (continued)

At recommended operating conditions with LVDD of 3.3 V ± 300 mv

Parameter/Condition	Symbol [1]	Min	Typ	Max	Unit
RXD[1:0], CRS_DV, RX_ER setup time to REF_CLK	$t_{RMRDVKH}$	4.0	—	—	ns
RXD[1:0], CRS_DV, RX_ER hold time to REF_CLK	$t_{RMRDXKH}$	2.0	—	—	ns
REF_CLK clock rise V_{IL}(min) to V_{IH}(max)	t_{RMXR}	1.0	—	4.0	ns
REF_CLK clock fall time V_{IH}(max) to V_{IL}(min)	t_{RMXF}	1.0	—	4.0	ns

Note:

1. The symbols used for timing specifications herein follow the pattern of $t_{\text{(first three letters of functional block)(signal)(state) (reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, $t_{RMRDVKH}$ symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{RMX} clock reference (K) going to the high (H) state or setup time. Also, $t_{RMRDXKL}$ symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) went invalid (X) relative to the t_{RMX} clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{RMX} represents the RMII (RM) reference (X) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

This figure provides the AC test load.

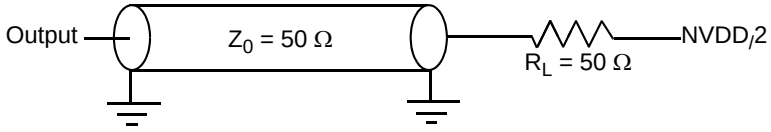

Figure 13. AC Test Load

This figure shows the RMII receive AC timing diagram.

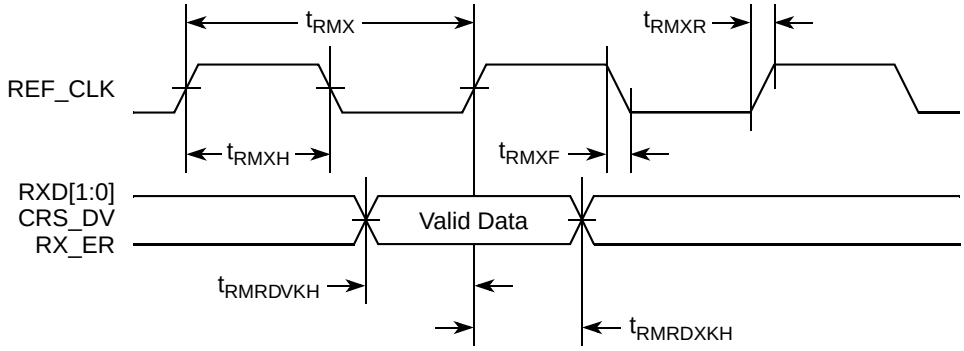

Figure 14. RMII Receive AC Timing Diagram

9.2.3 RGMII and RTBI AC Timing Specifications

This table presents the RGMII and RTBI AC timing specifications.

Table 29. RGMII and RTBI AC Timing Specifications

At recommended operating conditions (see Table 2)

Parameter/Condition	Symbol [1]	Min	Typ	Max	Unit
Data to clock output skew (at transmitter)	t_{SKRGT}	–0.6	—	0.6	ns
Data to clock input skew (at receiver) [2]	t_{SKRGT}	1.0	—	2.6	ns

This figure shows the MII management AC timing diagram.

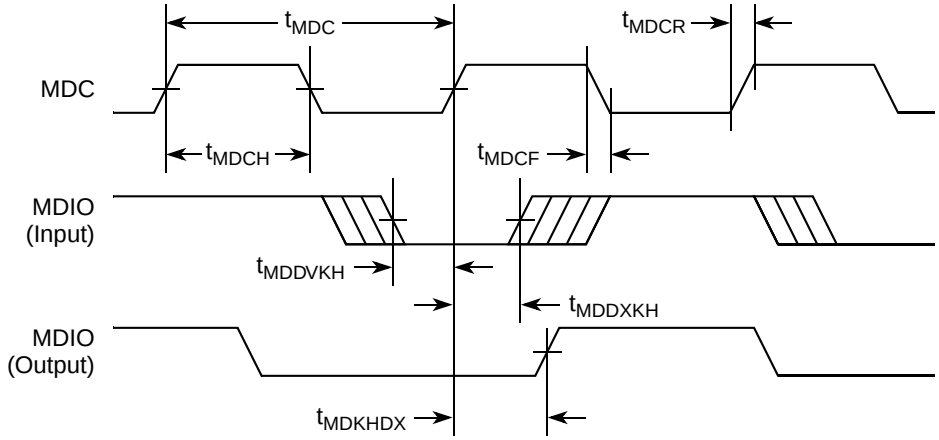

Figure 16. MII Management Interface Timing Diagram

9.4 1588 Timer Specifications

This section describes the DC and AC electrical specifications for the 1588 timer.

9.4.1 1588 Timer DC Specifications

This table provides the 1588 timer DC specifications.

Table 32. GPIO DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	V_{OH}	I_{OH} = –8.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 8.0 mA	—	0.5	V
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V
Input high voltage	V_{IH}	—	2.0	NVDD + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	0 V ≤ V_{IN} ≤ NVDD	—	± 5	μA

9.4.2 1588 Timer AC Specifications

This table provides the 1588 timer AC specifications.

Table 33. 1588 Timer AC Specifications

Parameter	Symbol	Min	Max	Unit	Note
Timer clock cycle time	t_{TMRCK}	0	70	MHz	1
Input setup to timer clock	t_{TMRCKS}	—	—	—	2, 3
Input hold from timer clock	t_{TMRCKH}	—	—	—	2, 3
Output clock to output valid	t_{GCLKNV}	0	6	ns	
Timer alarm to output valid	t_{TMRAL}	—	—	—	2

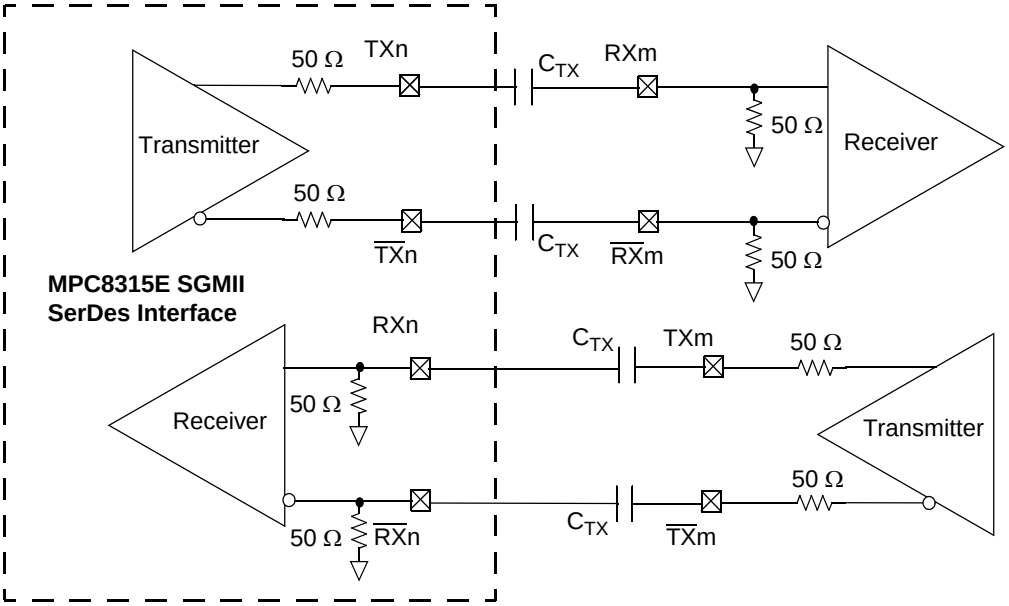

Figure 17. 4-Wire AC-Coupled SGMII Serial Link Connection Example

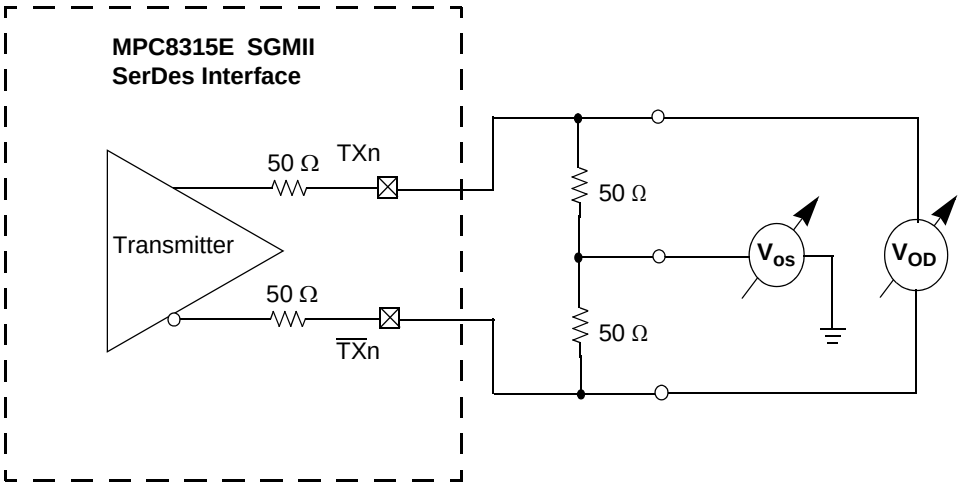

Figure 18. SGMII Transmitter DC Measurement Circuit

Table 36. SGMII DC Receiver Electrical Characteristics

Parameter		Symbol	Min	Typ	Max	Unit	Note
Supply Voltage		XCOREVDD	0.95	1.0	1.05	V	—
DC Input voltage range		—	N/A			—	1
Input differential voltage	EQ = 0	$V_{RX\_DIFFp-p}$	100	—	1200	mV	2, 4
	EQ = 1		175	—			
Loss of signal threshold	EQ = 0	VLOS	30	—	100	mV	3, 4
	EQ = 1		65	—	175		

Table 38. SGMII Receive AC Timing Specifications

At recommended operating conditions with XCOREVDD = 1.0V ± 5%.

Parameter	Symbol	Min	Typ	Max	Unit	Note
Deterministic Jitter Tolerance	JD	0.37	—	—	UI p-p	1
Combined Deterministic and Random Jitter Tolerance	JDR	0.55	—	—	UI p-p	1
Sinusoidal Jitter Tolerance	JSIN	0.1	—	—	UI p-p	1
Total Jitter Tolerance	JT	0.65	—	—	UI p-p	1
Bit Error Ratio	BER	—	—	10^{-12}		—
Unit Interval	UI	799.92	800	800.08	ps	2
AC Coupling Capacitor	C_{TX}	5	—	200	nF	3

Note:

1. Measured at receiver.
2. Each UI is 800 ps ± 100 ppm.
3. The external AC coupling capacitor is required. It's recommended to be placed near the device transmitter outputs.
4. Refer to RapidIO™ 1x/4x LP Serial Physical Layer Specification for interpretation of jitter specifications.

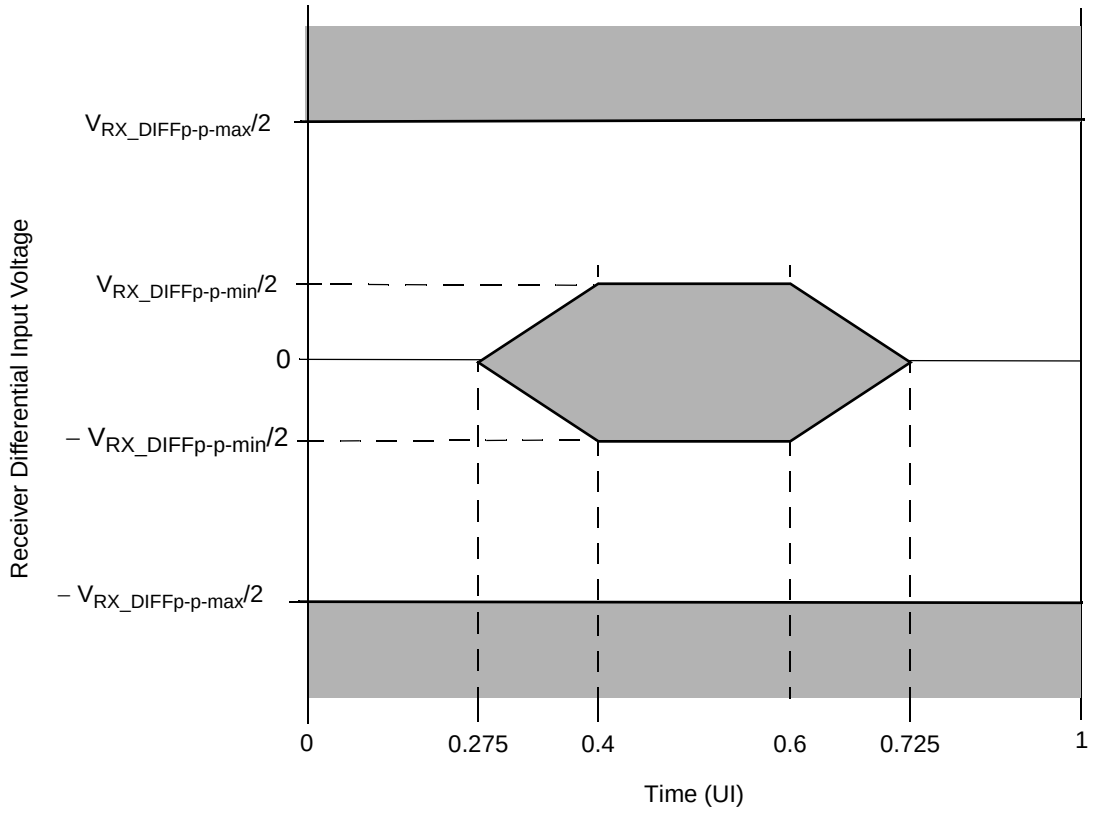

Figure 19. SGMII Receiver Input Compliance Mask

Table 41. USB_CLK_IN DC Electrical Characteristics

Parameter	Symbol	Min	Max	Unit
Input high voltage	V_{IH}	2.7	NV_{DD} + 0.3	V
Input low voltage	V_{IL}	–0.3	0.4	V

This table provides the USB clock input (USB_CLK_IN) AC timing specifications.

Table 42. USB_CLK_IN AC Timing Specifications

Parameter/Condition	Conditions	Symbol	Min	Typical	Max	Unit
Frequency range	—	$f_{USB\_CLK\_IN}$	—	24	—	MHz
Clock frequency tolerance	—	t_{CLK_TOL}	–0.005	0	0.005	%
Reference clock duty cycle	Measured at 1.6 V	t_{CLK_DUTY}	40	50	60	%
Total input jitter/Time interval error	Peak to peak value measured with a second order high-pass filter of 500 KHz bandwidth	t_{CLK_PJ}	—	—	200	ps

11 Local Bus

This section describes the DC and AC electrical specifications for the local bus interface of the MPC8314E.

11.1 Local Bus DC Electrical Characteristics

This table provides the DC electrical characteristics for the local bus interface.

Table 43. DC Electrical Characteristics (when Operating at 3.3 V)

Parameter	Symbol	Min	Max	Unit
Output high voltage (NVDD = min, I_{OH} = –2 mA)	V_{OH}	NVDD – 0.2	—	V
Output low voltage (NVDD = min, I_{OL} = 2 mA)	V_{OL}	—	0.2	V
Input high voltage	V_{IH}	2	NVDD + 0.3	V
Input low voltage	V_{IL}	–0.3	0.8	V
Input high current (V_{IN} = 0 V or V_{IN} = NVDD)	I_{IN}	—	±5	μA

11.2 Local Bus AC Electrical Specifications

This table describes the general timing parameters of the local bus interface of the MPC8314E.

Table 44. Local Bus General Timing Parameters

Parameter	Symbol [1]	Min	Max	Unit	Note
Local bus cycle time	t_{LBK}	15	—	ns	2
Input setup to local bus clock	t_{LBIVKH}	7	—	ns	3, 4

Table 44. Local Bus General Timing Parameters (continued)

Parameter	Symbol [1]	Min	Max	Unit	Note
Input hold from local bus clock	t_{LBIXKH}	1.0	—	ns	3, 4
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT1}$	1.5	—	ns	5
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT2}$	3	—	ns	6
LALE output fall to LAD output transition (LATCH hold time)	$t_{LBOTOT3}$	2.5	—	ns	7
Local bus clock to output valid	t_{LBKHOV}	—	3	ns	3
Local bus clock to output high impedance for LAD	t_{LBKHOZ}	—	4	ns	8
LALE output rise to LCLK negative edge	$t_{LALEHOV}$	—	3.0	ns	

Note:

1. The symbols used for timing specifications herein follow the pattern of $t_{\text{(First two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(First two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, $t_{LBIXKH1}$ symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the t_{LBK} clock reference (K) goes high (H), in this case for clock one(1). Also, t_{LBKHOX} symbolizes local bus timing (LB) for the t_{LBK} clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.
2. All timings are in reference to falling edge of LCLK0 (for all outputs and for $\overline{\text{LGTA}}$ and LUPWAIT inputs) or rising edge of LCLK0 (for all other inputs).
3. All signals are measured from NVDD/2 of the rising/falling edge of LCLK0 to 0.4 × NVDD of the signal in question for 3.3-V signaling levels.
4. Input timings are measured at the pin.
5. $t_{LBOTOT1}$ should be used when RCWH[LALE] is not set and the load on LALE output pin is at least 10pF less than the load on LAD output pins.
6. $t_{LBOTOT2}$ should be used when RCWH[LALE] is set and the load on LALE output pin is at least 10pF less than the load on LAD output pins.
7. $t_{LBOTOT3}$ should be used when RCWH[LALE] is set and the load on LALE output pin equals to the load on LAD output pins.
8. For active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.

This figure provides the AC test load for the local bus.

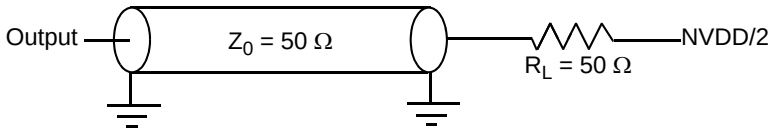

Figure 23. Local Bus AC Test Load

Figure 24 through Figure 26 show the local bus signals.

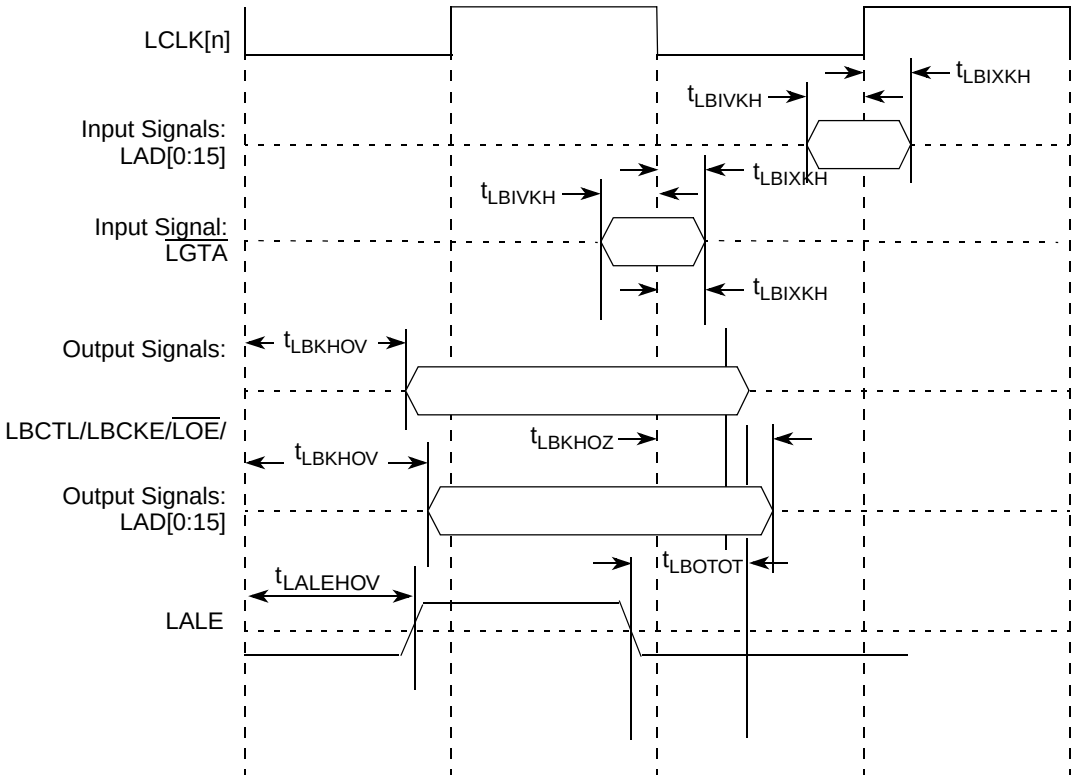

Figure 24. Local Bus Signals, Nonspecial Signals Only

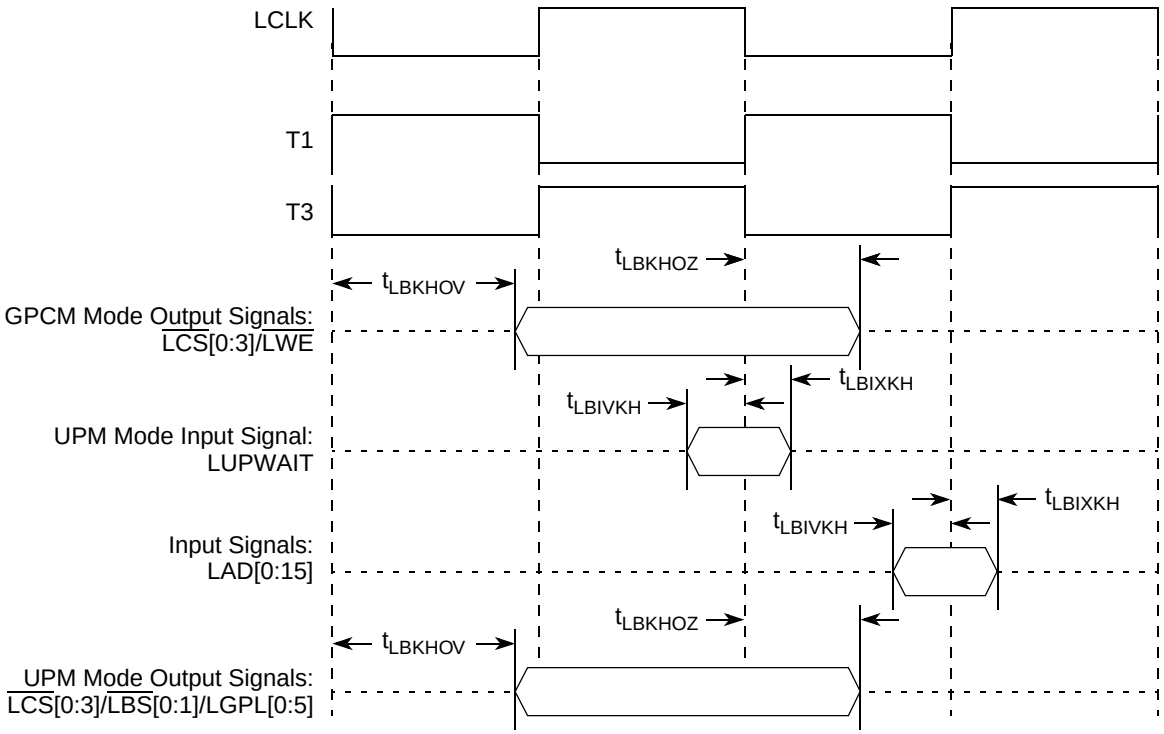

Figure 25. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 2

This figure provides the test access port timing diagram.

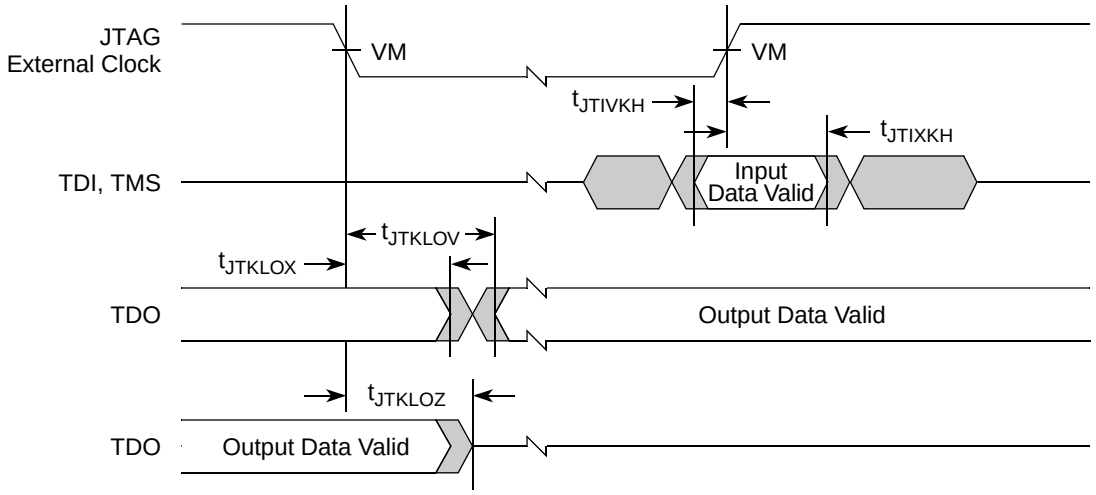

Figure 31. Test Access Port Timing Diagram

13 I²C

This section describes the DC and AC electrical characteristics for the I²C interface of the MPC8314E.

13.1 I²C DC Electrical Characteristics

This table provides the DC electrical characteristics for the I²C interface.

Table 47. I²C DC Electrical Characteristics

At recommended operating conditions with NVDD of 3.3 V ± 300 mv

Parameter	Symbol	Min	Max	Unit	Note
Input high voltage level	V_{IH}	0.7 × NVDD	NVDD + 0.3	V	—
Input low voltage level	V_{IL}	–0.3	0.3 × NVDD	V	—
Low level output voltage	V_{OL}	0	0.2 × NVDD	V	1
High level output voltage	V_{OH}	0.8 × NVDD	NVDD + 0.3	V	—
Output fall time from V_{IH}(min) to V_{IL}(max) with a bus capacitance from 10 to 400 pF	t_{I2KLKV}	20 + 0.1 × C_B	250	ns	2
Pulse width of spikes which must be suppressed by the input filter	t_{I2KHKL}	0	50	ns	3
Capacitance for each I/O pin	C_I	—	10	pF	—
Input current (0 V ≤V_{IN} ≤ NVDD)	I_{IN}	—	± 5	μA	4

Note:

1. Output voltage (open drain or open collector) condition = 3 mA sink current.
2. C_B = capacitance of one bus line in pF.
3. See the *MPC8315E PowerQUICC II Pro Integrated Host Processor Family Reference Manual* for information on the digital filter used.
4. I/O pins obstruct the SDA and SCL lines if NVDD is switched off.

Table 50. PCI AC Timing Specifications at 66 MHz (continued)

Parameter	Symbol [1]	Min	Max	Unit	Note
Input hold from clock	t_{PCIXKH}	0	—	ns	2, 4

Note:

1. Note that the symbols used for timing specifications herein follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{PCIVKH} symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI_SYNC_IN clock, t_{SYS}, reference (K) going to the high (H) state or setup time. Also, t_{PCRHFV} symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
2. See the timing measurement conditions in the *PCI 2.3 Local Bus Specifications*.
3. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
4. Input timings are measured at the pin.

This table shows the PCI AC Timing Specifications at 33 MHz.

Table 51. PCI AC Timing Specifications at 33 MHz

Parameter	Symbol [1]	Min	Max	Unit	Note
Clock to output valid	t_{PCKHOV}	—	11	ns	2
Output hold from clock	t_{PCKHOX}	2	—	ns	2
Clock to output high impedance	t_{PCKHOZ}	—	14	ns	2, 3
Input setup to clock	t_{PCIVKH}	4.0	—	ns	2, 4
Input hold from clock	t_{PCIXKH}	0	—	ns	2, 4

Note:

1. Note that the symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{PCIVKH} symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI_SYNC_IN clock, t_{SYS}, reference (K) going to the high (H) state or setup time. Also, t_{PCRHFV} symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
2. See the timing measurement conditions in the *PCI 2.3 Local Bus Specifications*.
3. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
4. Input timings are measured at the pin.

This figure provides the AC test load for PCI.

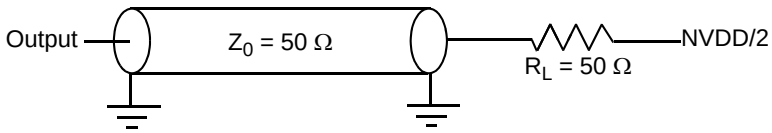

Figure 34. PCI AC Test Load

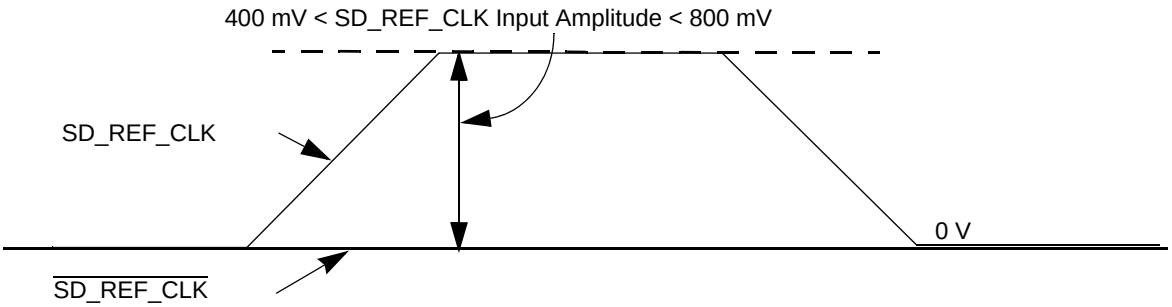

Figure 41. Single-Ended Reference Clock Input DC Requirements

15.2.3 Interfacing With Other Differential Signaling Levels

With on-chip termination to XCOREVSS, the differential reference clocks inputs are HCSL (High-Speed Current Steering Logic) compatible DC-coupled.

Many other low voltage differential type outputs like LVDS (Low Voltage Differential Signaling) can be used but may need to be AC-coupled due to the limited common mode input range allowed (100 to 400 mV) for DC-coupled connection.

LVPECL outputs can produce signal with too large amplitude and may need to be DC-biased at clock driver output first, then followed with series attenuation resistor to reduce the amplitude, in addition to AC-coupling.

NOTE

Figure 42–Figure 45 are for conceptual reference only. Due to the fact that clock driver chip's internal structure, output impedance and termination requirements are different between various clock driver chip manufacturers, it’s very possible that the clock circuit reference designs provided by clock driver chip vendor are different from what is shown below. They might also vary from one vendor to the other. Therefore, Freescale Semiconductor can neither provide the optimal clock driver reference circuits, nor guarantee the correctness of the following clock driver connection reference circuits. The system designer is recommended to contact the selected clock driver chip vendor for the optimal reference circuits with the MPC8315E SerDes reference clock receiver requirement provided in this document.

assumes that the LVPECL clock driver's output impedance is 50Ω. R1 is used to DC-bias the LVPECL outputs prior to AC-coupling. Its value could be ranged from 140Ω to 240Ω depending on clock driver vendor's requirement. R2 is used together with the SerDes reference clock receiver's 50-Ω termination resistor to attenuate the LVPECL output's differential peak level such that it meets the MPC8315E SerDes reference clock's differential input amplitude requirement (between 200mV and 800mV differential peak). For example, if the LVPECL output's differential peak is 900mV and the desired SerDes reference clock input amplitude is selected as 600mV, the attenuation factor is 0.67, which requires R2 = 25Ω. Please consult clock driver chip manufacturer to verify whether this connection scheme is compatible with a particular clock driver chip.

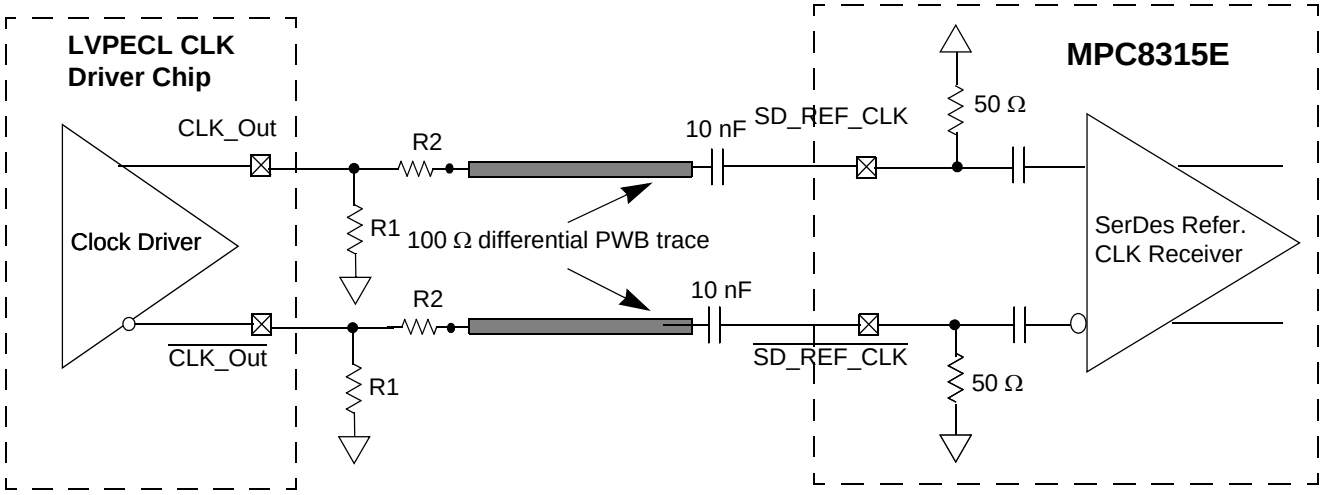

Figure 44. AC-Coupled Differential Connection with LVPECL Clock Driver (Reference Only)

This figure shows the SerDes reference clock connection reference circuits for a single-ended clock driver. It assumes the DC levels of the clock driver are compatible with MPC8315E SerDes reference clock input's DC requirement.

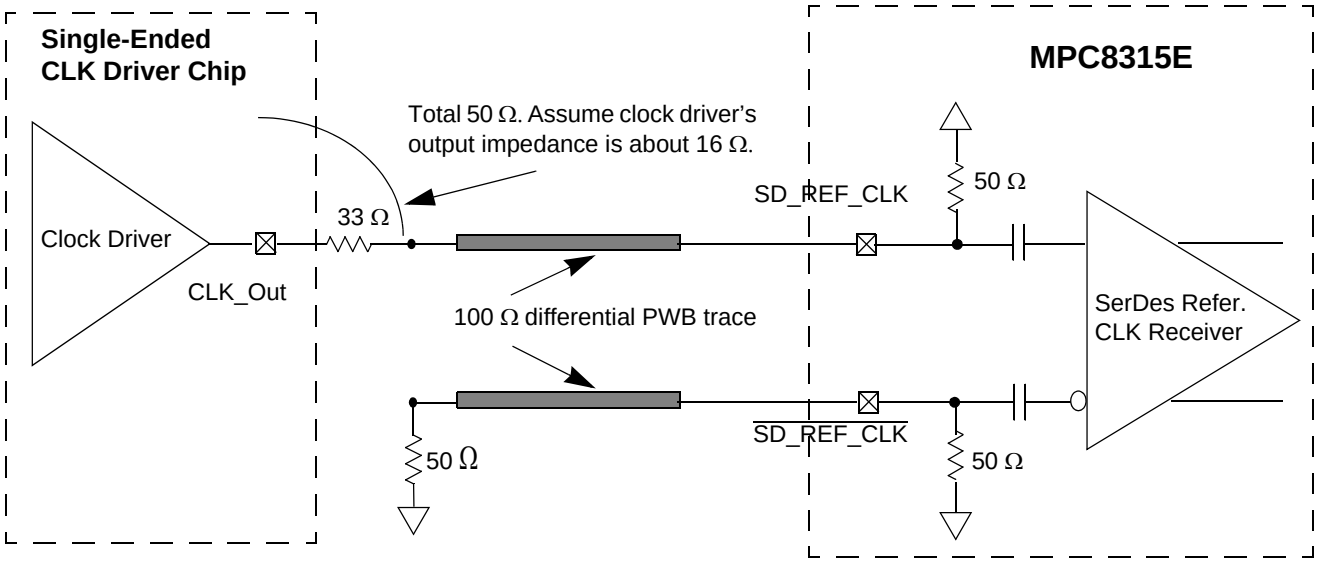

Figure 45. Single-Ended Connection (Reference Only)

16 PCI Express

This section describes the DC and AC electrical specifications for the PCI Express bus of the MPC8315E.

16.1 DC Requirements for PCI Express SD_REF_CLK and SD_REF_CLK

For more information, see Section 15.2, "SerDes Reference Clocks."

16.2 AC Requirements for PCI Express SerDes Clocks

This table lists the PCI Express SerDes clock AC requirements.

Table 53. SD_REF_CLK and SD_REF_CLK AC Requirements

Symbol	Parameter Description	Min	Typ	Max	Unit	Note
t_{REF}	REFCLK cycle time	—	10	—	ns	—
t_{REFCJ}	REFCLK cycle-to-cycle jitter. Difference in the period of any two adjacent REFCLK cycles.	—	—	100	ps	—
t_{REFPJ}	Phase jitter. Deviation in edge location with respect to mean edge location.	–50	—	50	ps	—

16.3 Clocking Dependencies

The ports on the two ends of a link must transmit data at a rate that is within 600 parts per million (ppm) of each other at all times. This is specified to allow bit rate clock sources with a ±300 ppm tolerance.

16.4 Physical Layer Specifications

Following is a summary of the specifications for the physical layer of PCI Express on this device. For further details as well as the specifications of the transport and data link layer please use the *PCI Express Base Specification*, Rev. 1.0a.

16.4.1 Differential Transmitter (TX) Output

This table defines the specifications for the differential output at all transmitters (TXs). The parameters are specified at the component pins.

Table 54. Differential Transmitter (TX) Output Specifications

Parameter	Symbol	Comments	Min	Typical	Max	Unit	Note
Unit interval	UI	Each UI is 400 ps ± 300 ppm. UI does not account for Spread Spectrum Clock dictated variations.	399.88	400	400.12	ps	1
Differential peak-to-peak output voltage	$V_{TX-DIFFp-p}$	$V_{TX-DIFFp-p} = 2*\|V_{TX-D+} - V_{TX-D-}\|$	0.8	—	1.2	V	2

Table 54. Differential Transmitter (TX) Output Specifications (continued)

Parameter	Symbol	Comments	Min	Typical	Max	Unit	Note
Maximum time to transition to a valid electrical idle after sending an electrical idle ordered set	$T_{TX-IDLE-SET-TO-IDLE}$	After sending an Electrical Idle ordered set, the Transmitter must meet all Electrical Idle Specifications within this time. This is considered a debounce time for the Transmitter to meet Electrical Idle after transitioning from L0.	—	—	20	UI	—
Maximum time to transition to valid TX specifications after leaving an electrical idle condition	$T_{TX-IDLE-TO-DIFF-DATA}$	Maximum time to meet all TX specifications when transitioning from Electrical Idle to sending differential data. This is considered a debounce time for the TX to meet all TX specifications after leaving Electrical Idle	—	—	20	UI	—
Differential return loss	$RL_{TX-DIFF}$	Measured over 50 MHz to 1.25 GHz.	12	—	—	dB	4
Common mode return loss	RL_{TX-CM}	Measured over 50 MHz to 1.25 GHz.	6	—	—	dB	4
DC differential TX impedance	$Z_{TX-DIFF-DC}$	TX DC Differential mode Low Impedance	80	100	120	Ω	—
Transmitter DC impedance	Z_{TX-DC}	Required TX D+ as well as D- DC Impedance during all states	40	—	—	Ω	—
Lane-to-Lane output skew	$L_{TX-SKEW}$	Static skew between any two Transmitter Lanes within a single Link	—	—	500 + 2 UI	ps	—
AC coupling capacitor	C_{TX}	All Transmitters shall be AC coupled. The AC coupling is required either within the media or within the transmitting component itself.	75	—	200	nF	8
Crosslink random timeout	$T_{crosslink}$	This random timeout helps resolve conflicts in crosslink configuration by eventually resulting in only one Downstream and one Upstream Port.	0	—	1	ms	7

Note:

1. No test load is necessarily associated with this value.
2. Specified at the measurement point into a timing and voltage compliance test load as shown in Figure 51 and measured over any 250 consecutive TX UIs. (Also refer to the transmitter compliance eye diagram shown in Figure 49.)
3. A T_{TX-EYE} = 0.70 UI provides for a total sum of deterministic and random jitter budget of $T_{TX-JITTER-MAX}$ = 0.30 UI for the transmitter collected over any 250 consecutive TX UIs. The $T_{TX-EYE-MEDIAN-to-MAX-JITTER}$ median is less than half of the total TX jitter budget collected over any 250 consecutive TX UIs. It should be noted that the median is not the same as the mean. The jitter median describes the point in time where the number of jitter points on either side is approximately equal as opposed to the averaged time value.
4. The transmitter input impedance shall result in a differential return loss greater than or equal to 12 dB and a common mode return loss greater than or equal to 6 dB over a frequency range of 50 MHz to 1.25 GHz. This input impedance requirement applies to all valid input levels. The reference impedance for return loss measurements is 50 Ω to ground for both the D+ and D– line (that is, as measured by a vector network analyzer with 50-Ω probes, see Figure 51). Note that the series capacitors, C_{TX}, is optional for the return loss measurement.
5. Measured between 20%–80% at transmitter package pins into a test load as shown in Figure 51 for both V_{TX-D+} and V_{TX-D-}.
6. See Section 4.3.1.8 of the *PCI Express Base Specifications*, Rev 1.0a.
7. See Section 4.2.6.3 of the *PCI Express Base Specifications*, Rev 1.0a.
8. MPC8315E SerDes transmitter does not have C_{TX} built-in. An external AC Coupling capacitor is required

Table 66. MPC8314E TEPBGA II Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Note
MEMC_MDM3	AF6	O	GVDD	—
MEMC_MDQS[0]	AF17	I/O	GVDD	—
MEMC_MDQS[1]	AG21	I/O	GVDD	—
MEMC_MDQS[2]	AG9	I/O	GVDD	—
MEMC_MDQS[3]	AF7	I/O	GVDD	—
MEMC_MBA[0]	AH16	O	GVDD	—
MEMC_MBA[1]	AH15	O	GVDD	—
MEMC_MBA[2]	AG15	O	GVDD	—
MEMC_MA0	AD15	O	GVDD	—
MEMC_MA1	AE15	O	GVDD	—
MEMC_MA2	AH14	O	GVDD	—
MEMC_MA3	AG14	O	GVDD	—
MEMC_MA4	AF14	O	GVDD	—
MEMC_MA5	AE14	O	GVDD	—
MEMC_MA6	AH13	O	GVDD	—
MEMC_MA7	AH12	O	GVDD	—
MEMC_MA8	AF13	O	GVDD	—
MEMC_MA9	AD13	O	GVDD	—
MEMC_MA10	AG12	O	GVDD	—
MEMC_MA11	AH11	O	GVDD	—
MEMC_MA12	AH10	O	GVDD	—
MEMC_MA13	AE12	O	GVDD	—
MEMC_MA14	AF11	O	GVDD	—
$\overline{\text{MEMC\_MWE}}$	AE5	O	GVDD	—
$\overline{\text{MEMC\_MRAS}}$	AD7	O	GVDD	—
$\overline{\text{MEMC\_MCAS}}$	AG4	O	GVDD	—
$\overline{\text{MEMC\_MCS}}$[0]	AH3	O	GVDD	—
$\overline{\text{MEMC\_MCS}}$[1]	AD5	O	GVDD	—
MEMC_MCKE	AE4	O	GVDD	3
MEMC_MCK[0]	AF4	O	GVDD	—
$\overline{\text{MEMC\_MCK}}$[0]	AF3	O	GVDD	—
MEMC_MCK[1]	AF1	O	GVDD	—
$\overline{\text{MEMC\_MCK}}$[1]	AE1	O	GVDD	—
MEMC_MODT[0]	AE3	O	GVDD	—
MEMC_MODT[1]	AD4	O	GVDD	—
MEMC_MVREF	AD12	I	GVDD	—

Table 66. MPC8314E TEPBGA II Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Note
GPIO_1/DMA_DACK1/GTM1_TIN2/GTM2_TIN1	A4	I/O	$NVDD1_{ON}$	—
GPIO_2/DMA_DONE1/GTM1_TGATE2/GTM2_TGATE1	K3	I/O	$NVDD4_{OFF}$	—
GPIO_3/GTM1_TIN3/GTM2_TIN4	K1	I/O	$NVDD4_{OFF}$	—
GPIO_4/GTM1_TGATE3/GTM2_TGATE4	K2	I/O	$NVDD4_{OFF}$	—
GPIO_5/GTM1_TOUT3/GTM2_TOUT1	L5	I/O	$NVDD4_{OFF}$	—
GPIO_6/GTM1_TIN4/GTM2_TIN3	L3	I/O	$NVDD4_{OFF}$	—
GPIO_7/GTM1_TGATE4/GTM2_TGATE3	L1	I/O	$NVDD4_{OFF}$	—
GPIO_8/USBDR_DRIVE_VBUS/GTM1_TIN1/GTM2_TIN2	M1	I/O	$NVDD4_{OFF}$	—
GPIO_9/USBDR_PWRFAULT/GTM1_TGATE1/GTM2_TGATE2	M2	I/O	$NVDD4_{OFF}$	—
GPIO_10/USBDR_PCTL0/GTM1_TOUT2/GTM2_TOUT1	M5	I/O	$NVDD4_{OFF}$	—
GPIO_11/USBDR_PCTL1/GTM1_TOUT4/GTM2_TOUT3	M4	I/O	$NVDD4_{OFF}$	—
SPI				
SPIMOSI/GPIO_15	W3	I/O	$NVDD1_{OFF}$	—
SPIMISO/GPIO_16	W4	I/O	$NVDD1_{OFF}$	—
SPICLK	Y1	I/O	$NVDD1_{OFF}$	—
SPISEL/GPIO_17	W2	I/O	$NVDD1_{OFF}$	—
Power and Ground Supplies				
GVDD	Y11, Y12, Y14, Y15, Y17, AC8, AC11, AC14, AC17, AD6, AD9, AD17, AE8, AE13, AE19, AF10, AF15, AF21, AG2, AG3, AG8, AG13, AG19, AH2	I	—	—
$LVDD1_{OFF}$	H6, J3, L6, L9, M9	I	—	—
$LVDD2_{ON}$	C11, D9, E10, F11, J12	I	—	—
$NVDD1_{OFF}$	U9, V9, W10, Y4, Y6, AA3, AB4	I	—	—
$NVDD1_{ON}$	B1, B2, C1, D5, E7, F5, F9, J11, K10	I	—	—
$NVDD2_{OFF}$	B22, B27, C19, E16, F15, F18, F21, F25, H25, J17, J18, J23, L20, M20	I	—	—
$NVDD2_{ON}$	L26, N19	I	—	—
$NVDD3_{OFF}$	U20, V20, V23, V26, W19, Y18, Y26, AA23, AA25, AC20, AC25, AD23, AE25, AG25, AG27, T27, U27	I	—	—
$NVDD4_{OFF}$	K4, L2, M6, N10	I	—	—

23.2 Core PLL Configuration

RCWL[COREPLL] selects the ratio between the internal coherent system bus clock (*csb_clk*) and the e300 core clock (*core_clk*). Table 72 shows the encodings for RCWL[COREPLL]. COREPLL values that are not listed in Table 72 should be considered as reserved.

NOTE

Core VCO frequency = core frequency × VCO divider
VCO divider has to be set properly so that the core VCO frequency is in the range of 400–800 MHz.

Table 72. e300 Core PLL Configuration

RCWL[COREPLL]			*core_clk* : *csb_clk* Ratio	VCO Divider[1]
0–1	2–5	6		
nn	0000	0	PLL bypassed (PLL off, *csb_clk* clocks core directly)	PLL bypassed (PLL off, *csb_clk* clocks core directly)
11	nnnn	n	N/A	N/A
00	0001	0	1:1	2
01	0001	0	1:1	4
00	0001	1	1.5:1	2
01	0001	1	1.5:1	4
00	0010	0	2:1	2
01	0010	0	2:1	4
00	0010	1	2.5:1	2
01	0010	1	2.5:1	4
00	0011	0	3:1	2
01	0011	0	3:1	4

1 Core VCO frequency = core frequency × VCO divider.

23.3 Suggested PLL Configurations

To simplify the PLL configurations, the MPC8314E might be separated into two clock domains. The first domain contain the CSB PLL and the core PLL. The core PLL is connected serially to the CSB PLL, and has the csb_clk as its input clock. The clock domains are independent, and each of their PLLs are configured separately. Both of the domains has one common input clock. Table 73 shows suggested PLL configurations for 33, 25, and 66 MHz input clocks.

Table 73. Suggested PLL Configurations

Conf. No.	SPMF	Core\PLL	Input Clock Frequency (MHz)	CSB Frequency (MHz)	Core Frequency (MHz)
1	0100	0000100	33.33	133.33	266.66
3	0010	0000100	66.67	133.33	266.66
4	0100	0000101	33.33	133.33	333.33
5	0101	0000101	25	125	312.5